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### **Datasheet**

## **F1 Smart Module**

July 2024 V1.2



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## Introduction

The F1 Smart Module (order part number SGW3501) is a compact OEM module equipped with BLE, Wi-Fi, LoRa(WAN), and LTE CAT-M1/NB1/NB2 to support various connectivity needs. Running on a MicroPythonprogrammable microcontroller with a nobarrier entry into the SG Wireless Ctrl. Cloud Platform, the module enables truly limitless IoT application development with multi-network creation flexibility and rapid scaling capacity.

The F1 Smart Module has four variants with various connectivity options, under each variant, there are two subvariants with advanced security element option.

• Multi-connectivity:

Wi-Fi 802.11b/g/n (2.4GHz)

Bluetooth BLE 5.0

Cellular LTE-CAT M1/NB1/NB2

Semtech LoRa(WAN) 868MHz/915MHz

- Powerful Espressif ESP32 S3 CPU
- MicroPython programmable with 27 IOs on module pads
- SMT-friendly semi-hole pins at module edges
- Operating temperature: 0°C to 85°C
- Advanced Security IC NXP SE050 (for "s" suffix models)
- Compact size-to-functionality ratio: 42.6mm x 17.6mm x 3.6mm

Order Part Nu mber	Description
SGW3531	F1s Smart Module: BLE, Wi-Fi, LoRa, LTE s Secure element
SGW3501	F1 Smart Module: BLE, Wi-Fi, LoRa, LTE
SGW3431	F1/Cs Cellular Module: BLE, Wi-Fi, LTE s Secure element
SGW3401	F1/C LoRa Module: BLE, Wi-Fi, LTE
SGW3231	F1/Ls LoRa Module: BLE, Wi-Fi, LoRa s Secure element
SGW3201	F1/L LoRa Module: BLE, Wi-Fi, LoRa

SGW3131	F1/Ws Wi-Fi BLE Module: BLE, Wi-Fi s Secure element
SGW3101	F1/W Wi-Fi BLE Module: BLE, Wi-Fi

## **General Features**

### a. Feature Specifications

#### **CPU**

- Xtensa® dual-core 32-bit LX7 microprocessor, up to 240Mhz
- On-chip 384KB ROM and 512KB SRAM, on-board 8MB PSRAM and 16MB Flash
- Deep Sleep Mode: 10μA

#### Wi-Fi/BLE

- Espressif ESP32-S3 on-chip RF frontend
- Wi-Fi: IEEE 802.11b/g/n (2.4GHz band); Data Rate: 1M up to 54Mbps (MCS7); Max
   Tx Power: 20dBm
- BLE: Bluetooth LE 5.0, Bluetooth mesh; Data Rate: 125kbps to 2Mbps; Max Tx
   Power: 20dBm

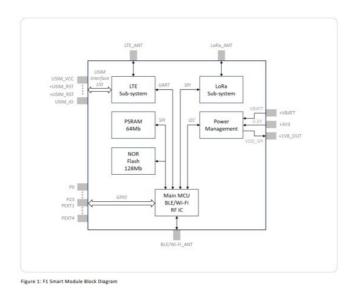
#### LTE

- Sequans Monarch2 GM02S for CAT-M1, CAT-NB1 and CAT-NB2 support
- LTE CAT-M1/NB1/NB2 transmit power up to +23dBm
- PTCRB and GCF 1.3 3GPP release 13 compliant; Operator Approval: Verizon, AT&T,
   T-Mobile, Vodafone, Orange

#### LoRa

- Semtech SX1262 RF transceiver, 868/915MHz LPWAN Module
- TX Power: Up to +22dBm; Sensitivity: -127dBm
- LoRaWAN stack Class A and Class C Device

### b. Block Diagram



# **Electrical Specifications**

# a. Absolute Rating and Operating Conditions

Table 1: Absolute Rating and Operating Conditions Specifications

Symbol	Parameter	Min	Тур	Max	Unit		
Absolute Rating							
+VBATT	Supply voltage to Sequans GM02S L TE module		5.0	5.8	V		
+3V3	Supply voltage to Espressif ESP32-S 3 and module main circuit	3.0	3.3	3.6	V		
+1V8_OU T*	SPI supply voltage (output) of SPI flas h and PSRAM for decoupling capacit or connection		1.8	2.3	V		
T(OPR)	Operating temperature	-40		85	°C		
Operating Conditions							
+VBATT	Supply voltage to Sequans GM02S L TE module	2.5	5.0	5.5	V		

+3V3	Supply voltage to Espressif ESP32-S 3 and module main circuit	3.2	3.3	3.4	V
+1V8_OU T*	SPI supply voltage (output) of SPI flas h and PSRAM for decoupling capacit or connection	1.7	1.8	1.9	V
CPU IO (3.	3V power domain, VDD=3.3V)				
VIH	Input high voltage for GPIOs	0.75 x VDD		VDD + 0.3	V
VIL	Input low voltage for GPIOs	-0.3		0.25 x VDD	V
VOH	Input high voltage for GPIOs	0.8 x V DD			V
VOL	Input low voltage for GPIOs			0.1 x V DD	V
Radio IO (	I.8V power domain)				
VIH	Input high voltage for GPIOs	1.26		1.8	V
VIL	Input low voltage for GPIOs	0		0.54	V
VOH	Input high voltage for GPIOs	1.44		1.8	V
VOL	Input low voltage for GPIOs	0		0.36	V

<sup>\*</sup> The +1V8\_OUT pin is to connect an external capacitor to the module internal SPI flash and PSRAM for a more robust VDD\_SPI supply. This pin should not be connected to any external circuits that may draw more than 20mA. Voltage of this pin will vary in module light sleep mode and approach zero in module deep sleep mode.

### b. Wi-Fi

Standard: 802.11b/g/n (2.4GHz ONLY) - 1T1R

Table 2: Wi-Fi Specifications

Parameter	Description	Min	Тур	Max	Unit				
General									
Freq. (EU)	Operating frequency (EU)	2.402		2.482	GHz				
Ch. (EU)	Channel (EU)	1		13					
Freq. (US)	Operating frequency (US)	2.402		2.472	GHz				
Ch. (US)	Channel (US)	1		11					
Power max. (EU/US)	Maximum power (EU/US)			20	dBm				
Тх	Tx								
Tx Power @ B – 1Mbps	Tx power at B mode with data rate  1Mbps		18	20	dBm				
EVM (Peak) @B – 1Mbp s	EVM(Peak) at B mode with data rat e 1Mbps			8	%				
Freq. Err. @ B – 1Mbps	Frequency error at B mode with dat a rate 1Mbps	-40	0	40	kHz				
Tx Power  @G – 54Mb ps	Tx power at G mode with data rate 54Mbps		16	20	dBm				
EVM (RMS)  @G - 54Mb ps	EVM(RMS) at G mode with data rat e 54Mbps			-25	dB				

Frequency error at G mode with dat a rate 54Mbps	-40	0	40	kHz
Tx power at N mode with data rate MCS7 and 20MHz bandwidth		15	20	dBm
EVM rms at N mode with data rate MCS7 and 20MHz bandwidth			-27	dB
Frequency error @ N mode with da ta rate MCS7 and 20MHz bandwidt h	-40	0	40	kHz
Tx power at B mode with data rate  1Mbps		18	20	dBm
Tx power at B mode with data rate 1Mbps		-92.0	-82.0	dBm
Tx power at G mode with data rate 54Mbps		-76.5	-66.0	dBm
Tx power at N mode with data rate MCS7 and 20MHz bandwidth		-71.4	-64.0	dBm
	a rate 54Mbps  Tx power at N mode with data rate MCS7 and 20MHz bandwidth  EVM rms at N mode with data rate MCS7 and 20MHz bandwidth  Frequency error @ N mode with da ta rate MCS7 and 20MHz bandwidt h  Tx power at B mode with data rate 1Mbps  Tx power at B mode with data rate 1Mbps  Tx power at G mode with data rate 54Mbps  Tx power at N mode with data rate	Tx power at N mode with data rate MCS7 and 20MHz bandwidth  EVM rms at N mode with data rate MCS7 and 20MHz bandwidth  Frequency error @ N mode with da ta rate MCS7 and 20MHz bandwidt h  Tx power at B mode with data rate 1Mbps  Tx power at B mode with data rate 1Mbps  Tx power at G mode with data rate 54Mbps  Tx power at N mode with data rate	Tx power at N mode with data rate MCS7 and 20MHz bandwidth  EVM rms at N mode with data rate MCS7 and 20MHz bandwidth  Frequency error @ N mode with data rate MCS7 and 20MHz bandwidth  Tx power at B mode with data rate 1Mbps  Tx power at B mode with data rate 1Mbps  Tx power at G mode with data rate 54Mbps  Tx power at N mode with data rate 54Mbps  Tx power at N mode with data rate 54Mbps	a rate 54Mbps  Tx power at N mode with data rate MCS7 and 20MHz bandwidth  EVM rms at N mode with data rate MCS7 and 20MHz bandwidth  Frequency error @ N mode with data rate MCS7 and 20MHz bandwidt h  Tx power at B mode with data rate 1Mbps  Tx power at B mode with data rate 1Mbps  Tx power at G mode with data rate 54Mbps  Tx power at N mode with data rate 54Mbps  Tx power at N mode with data rate 54Mbps

# c. Bluetooth

Standard: BLE 5.0 - 1T1R

**Table 3: Bluetooth Specifications** 

Parameter	Description	Min	Тур	Max	Unit	
General						
Freq.	Operating frequency	2.4000		2.4835	GHz	
Ch.	Channel	0		39		
Power max.	Maximum power			20	dBm	
Тх						
Tx Power @Ch.37 – 1 Mbps	Tx power at channel 37 (freq.=2402 MHz) with data rate 1Mbps		17	20	dBm	
Freq. Err. @ Ch.37 – 1M bps	Frequency error at channel 37 (freq.=2402MHz) with data rate 1M bps	-50	0	50	%	
Tx Power @Ch.38 – 1 Mbps	Tx power at channel 38 (freq.=2426 MHz) with data rate 1Mbps		17	20	kHz	
Freq. Err. @ Ch.38 – 1M bps	Frequency error at channel 38 (freq.=2426MHz) with data rate 1M bps	-50	0	50	dBm	
Tx Power @Ch.39 – 1 Mbps	Tx power at channel 39 (freq.=2480 MHz) with data rate 1Mbps		17	20	dBm	
Freq. Err. @ Ch.39 – 1M bps	Frequency error at channel 39 (freq.=2480MHz) with data rate 1M bps	-50	0	50	kHz	

Rx				
Rx Sens. @ Ch.38 – 2M bps	Tx power at channel 38 (freq.=2426 MHz) with data rate 2Mbps	-93.5		dBm
Rx Sens. @ Ch.38 – 1M bps	Tx power at channel 38 (freq.=2426 MHz) with data rate 1Mbps	-97.5	-70.0	dBm
Rx Sens. @ Ch.38 – 500 kbps	Tx power at channel 38 (freq.=2426 MHz) with data rate 500kbps	-100.0		dBm

## d. LTE

Standard: CAT-M1, CAT-NB1, CAT-NB2
Table 4: LTE Frequency Bands (in MHz)

Ban d N o.	Duplex Type	Uplink Fre quency (MHz)	Uplink Ba ndwidth ( MHz)	Downlink Frequenc y (MHz)	Downlink Bandwidt h (MHz)	For L TE-M	For NB-Io T
1	FDD	1920 – 19 80	60	2110 – 21 70	60	1	1
2	FDD	1850 – 19 10	60	1930 – 19 90	60	1	1
3	FDD	1710 – 17 85	75	1805 – 18 80	75	1	1
4	FDD	1710 – 17 55	45	2110 – 21 55	45	1	/

5	FDD	824 – 849	25	869 – 894	25	1	1
8	FDD	880 – 915	35	925 – 960	35	1	1
12	FDD	699 – 716	17	729 – 746	17	1	1
13	FDD	777 – 787	10	746 – 756	10	1	1
14	FDD	788 – 798	10	758 – 768	10	1	1
17	FDD	704 – 716	12	734 – 746	12	1	1
18	FDD	815 – 830	15	860 – 875	15	1	✓
19	FDD	830 – 845	15	875 – 890	15	1	✓ <b></b>
20	FDD	832 – 862	30	791 – 821	30	1	1
25	FDD	1850 – 19 15	65	1930 – 19 95	65	1	1
26	FDD	814 – 849	35	859 – 894	35	1	1
28	FDD	703 – 748	45	758 – 803	45	1	✓

66	FDD	1710 – 17 80	70	2110 – 22 00	90	1	<b>√</b>
85	FDD	698 – 716	18	728 – 746	18	1	<b>\</b>

# **Table 5: LTE Specifications**

Parameter	Description	Min	Тур	Max	Unit			
General								
Power max.	Maximum power			23	dBm			
Тх								
Tx power @Band 8 (90 0MHz GSM)	Tx power at Band 8 (900 MHz GSM)		22	23	dBm			
Tx power @Band 2 (19 00MHz PCS)	Tx power at Band 2 (190 0MHz PCS)		22	23	dBm			
Rx								
Rx sens. @Band 8 (90 0MHz GSM)	Rx sensitivity at Band 8 (900MHz GSM)		-103	-100	dBm			
Rx sens. @Band 2 (19 00MHz PCS)	Rx sensitivity at Band 2 (1900MHz PCS)		-103	-100	dBm			

## e. LoRa

Mode: LoRa RAW mode and LoRa WAN mode LoRaWAN Node Type: Class Type A,

Class Type C Frequency Band: EU868, US915

Table 6: LoRa Specifications

Parameter Description Min Typ Max Unit
--

General						
Freq. (EU)	Frequency band (EU	863		870	GHz	
Freq. (US)	Frequency band (US	902		928	GHz	
Power max. (EU)	Maximum power (EU			15	dBm	
Power max. (US)	Maximum power (US			22	dBm	
Тх	Тх					
Tx power (Tx tone) @866. 4MHZ [EU868 band]	Tx power (Tx tone) a t 866.4MHz		14	15	dBm	
Tx power (Tx tone) @918. 2MHZ [US915 band]	Tx power (Tx tone) a t 918.2MHz		21	22	%	
Rx						
Rx Sens. @freq=866.4MHz, BW=50 0kHz, SF=12	Rx sensitivity at 866.  4MHz, 500kHz band  width and SF=12		-127		dBm	
Rx Sens. @freq=866.4MHz, BW=50 0kHz, SF=12	Rx sensitivity at 866.  4MHz, 500kHz band width and SF=12		-127		dBm	

# **Module Interface**

# a. Power Management

Table 7: Power Consumption by Mode of Operation

Mode of Operation	Min	Тур	Max	Unit
Idle (no radio but MicroPython is running)		30		mA
Light sleep (wake up or restart is required for Micr oPython to run)		800		μΑ
Deep sleep (wake up or restart is required for Micr oPython to run)		10		μΑ

## **b. Memory Allocation**

Module OS firmware, OTA and user space sizes:

• Module OS firmware: 2,560Kb

OTA1 space: 2,560KbOTA2 space: 2,560Kb

• User space: 8Mb

## **Mechanical Data**

## a. Mechanical Specification

All pins have a pin width of 0.7mm with the exception of pin VBATT (pin #A4) with pin width 1.0mm.

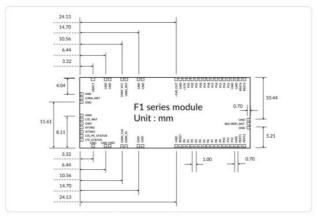
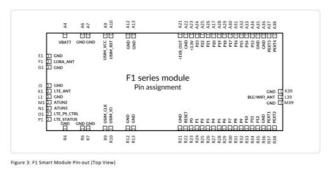


Figure 2: F1 Smart Module Pin Dimensions, Pin Pitches and Pin Locations (Top View)

### b. Module Pin-out



**Table 8: F1 Smart Module Pin-out** 

Pin N umber	Pin Na me	MCU Pin	LTE Mod ule Pin	Туре	Description
R4	GND			Power	Ground signal
R6	GND			Power	Ground signal
R7	GND			Power	Ground signal
R9	USIM_C LK		SIM0_CL	Analog I/O	USIM interface I/O to GM02S
R10	USIM_I O		SIM0_IO	Digital I/	USIM interface I/O to GM02S
R12	GND			Power	Ground signal
R13	GND			Power	Ground signal
R21	GND			Power	Ground signal
R22	RESET	CHIP_P U		Analog I/O	Reset pin to ESP32-S3 for mod ule reset
R23	P0	U0RXD		Analog I/O	UART0 RXD to ESP32-S3
R24	P1	U0TXD		Analog I/O	UART0 TXD to ESP32-S3

R25	P2	GPIO0	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3
R26	P3	GPIO4	Analog I/O or D igital I/	Analog I/O or Digital I/O to ESP 32-S3
R27	P4	MTDO	Digital I/	Digital I/O to ESP32-S3
R28	P5	GPIO5	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3
*R29	P6	GPIO6		Reserved – Leave floating, do not connect

R30	P7	GPIO3	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3
R31	P8	GPIO46	Digital I/	Digital I/O to ESP32-S3
R32	P9	GPIO45	Digital I/	Digital I/O to ESP32-S3
R33	P10	MTCK	Digital I/	Digital I/O to ESP32-S3

R34	P11	GPIO11	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3
R35	P12	GPIO21	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3
R36	GND		Power	Ground signal
R37	PEXT1	GPIO1	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3
R38	PEXT2	GPIO12	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3
M39	GND		Power	Ground signal
L39	BLE/WI FI_ANT		RF I/O	RF interface to ESP32-S3 for B LE and/or Wi-Fi interface
K39	GND		Power	Ground signal
A38	PEXT4	GPIO14	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3

A37	PEXT3	GPIO13	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3
A36	GND		Power	Ground signal
A35	GND		Power	Ground signal
A34	P13	GPIO20	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3 /USB OTG D+
A33	P14	GPIO19	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3 /USB OTG D-
A32	P15	GPIO38	Digital I/	Digital I/O to ESP32-S3
A31	P16	GPIO41	Digital I/	Digital I/O to ESP32-S3
A30	P17	GPIO2	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3
A29	P18	GPIO10	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3

A28	P19	GPIO15	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3
A27	P20	GPIO16	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3
A26	P21	GPIO17	Analog I/O or D igital I/ O	Analog I/O or Digital I/O to ESP 32-S3
A25	P22	GPIO18	Analog I/O or D igital I/	Analog I/O or Digital I/O to ESP 32-S3
A24	P23	GPIO42	Digital I/	Digital I/O to ESP32-S3
A23	+3.3V	VDD3P3 _CPU V DD3P3_ RTC VD D3P3 V DDA	Power	Voltage supply to ESP32-S3 an d module main circuit
A22	GND		Power	Ground signal

A21	+1.8V_ OUT	VDD_SP		Power	Voltage supply VDD_SPI to ES P32-S3 for SPI flash and PSRA M
A13	GND			Power	Ground signal
A12	GND			Power	Ground signal
A10	USIM_R ST		SIM0_RS TN	Digital I/	USIM interface I/O to GM02S
A9	USIM_V CC		SIMO_VC	Power	USIM voltage supply to GM02S
A7	GND			Power	Ground signal
A6	GND			Power	Ground signal
A4	+VBATT		VBAT	Power	Voltage supply to GM02S
E1	GND			Power	Ground signal
F1	LORA_ ANT			RF I/O	RF interface to SX1262 for LoR a interface
G1	GND			Power	Ground signal
J1	GND			Power	Ground signal
K1	LTE_AN T		LTE_AN T	RF I/O	RF interface to GM02S for LTE CAT-M1/CAT- NB1/CAT-NB2 int erface
L1	GND			Power	Ground signal
M1	ATUN2		GPIO34/ ANT_TU NE0	Analog I/O	ANT_TUNE I/O to GM02S

N1	ATUN3	GPIO35/ ANT_TU NE1	Analog I/O	ANT_TUNE I/O to GM02S
O1	LTE_PS _CTRL	GPIO2/ P S_STATU S	Digital I/	Power saving status I/O from G M02S
P1	LTE_ST ATUS	GPIO1/S TATUS_L ED	Digital I/	LTE status I/O from GM02S

# c. Recommended PCB Landing Pattern

All pins have a pin width of 0.7mm with the exception of pin VBATT (pin #A4) with pin width 1.0mm.

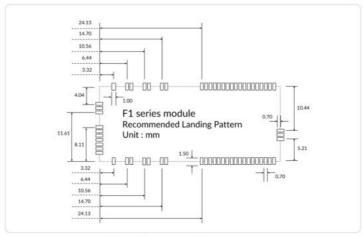
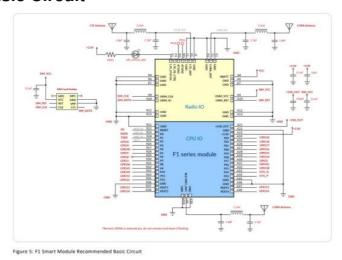
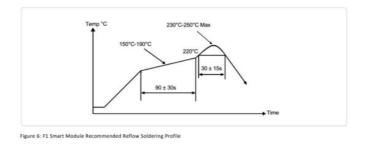


Figure 4: F1 Smart Module Recommended PCB Landing Pattern (Top View)

## d. Recommended Basic Circuit



e. Recommended Soldering Profile



# **MicroPython Application Development on F1**

## a. Device Programming via UART

- By default, the F1 Smart Module runs an interactive python REPL (Read-Eval-Print-Loop) on UART0 which is connected to P0 (RX) and P1 (TX) running at 115200 baud.
- The Module can be connected via a development board or any USB UART adapter.
   Code can be run via the REPL and the SG Wireless CtrlR. Visual Studio Code plug-in can also be used to upload code to the board.

## b. Module-supported Libraries

Table 9: F1 Smart Module Supported Libraries

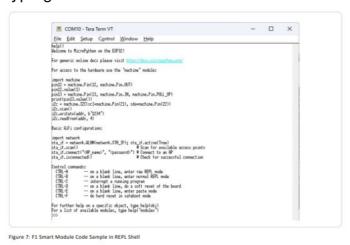
Library	Min
Python Standard Libr aries*	array, aysncio, binascii, builtins, cmath, collections, errno, gc, gzip, hashlib, heapq, io, json, math, os, platform, random, re, select, socket, ssl, struct, sys, time, zlib, _thread
MicroPython-specific Libraries*	Bluetooth, btree, cryptolib, deflate, framebuf, machine, microp ython, neopixel, network, uctypes, esp, esp32
F1 Smart Module-spe cific Libraries†	Ite: Ready-to-use LTE CAT-M1/NB1/NB2 library Iora: Ready-to-use LoRa RAW and full stack LoRa WAN devi ce Class A, Class C library ctrl: Ready-to-use Ctrl Cloud Platf orm client library

<sup>\*</sup> MicroPython documentation library with API function calls (https://docs.micropython.org/en/latest/library/).

<sup>†</sup> SG Wireless F1 Smart Module documentation library with API function calls.

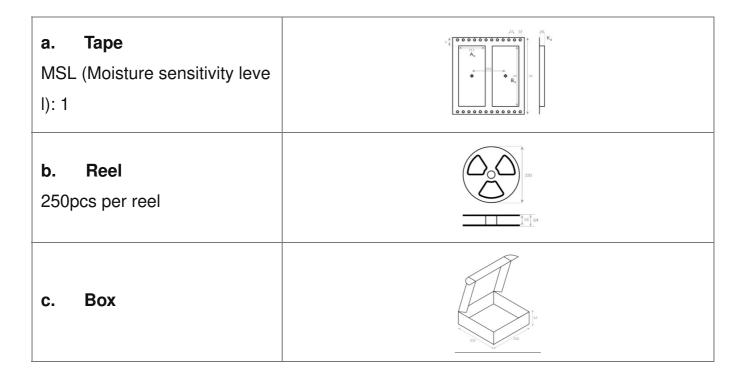
## c. MicroPython Capability – REPL (Read-Eval-Print Loop)

The MicroPython-ready F1 Smart Module carries the REPL shell that that can execute codes in realtime, as well as enable section-by-section of code execution through a copy-and-paste function, both of which facilitate real-time debugging and instant application code prototyping.



# **Product Packaging**

Modules are packed in tape-and-reel packaging and shipped out in carton boxes.



## Certification

#### a. CE Statements

EU Declaration of Conformity (DOC)

Hereby, SG Wireless Limited declares that the F1 Smart Module series is in compliance

with Radio Equipment Directive (RED) 2014/53/EU.

The full text of the EU declaration of conformity is available at the following Internet address: <a href="https://docs.sgwireless.com">https://docs.sgwireless.com</a>

### RF exposure statement

RF exposure information: The Maximum Permissible Exposure (MPE) level has been calculated based on a istance of d=20cm between the device and the human body. To maintain compliance with RF exposure requirement, use product that maintain a 20cm distance between the device and human body.

## CE marking and labeling

By complying to CE standard, all modules are laser printed with "CE" marking and part number at surface of the module shield can; and manufacturer information is printed with label at shipping box/packages.

### CE marking on module:



Manufacturer information at shipping package/box:



### b. FCC Statements

This device complies with Part 15 of the FCC Rules. Operation is subject to the following two conditions:

1. This device may not cause harmful interference.

2. This device must accept any interference received, including interference that may cause undesired operation.

**CAUTION:** Changes or modifications not expressly approved by the party responsible for compliance could void the user's authority to operate the equipment.

**NOTE:** This equipment has been tested and found to comply with the limits for a Class B digital device, pursuant to Part 15 of the FCC Rules. These limits are designed to provide reasonable protection against harmful interference in a residential installation. This equipment generates uses and can radiate radio frequency energy and, if not installed and used in accordance with the instructions, may cause harmful interference to radio communications. However, there is no guarantee that interference will not occur in a particular installation. If this equipment does cause harmful interference to radio or television reception, which can be determined by turning the equipment off and on, the user is encouraged to try to correct the interference by one or more of the following measures:

- Reorient or relocate the receiving antenna.
- Increase the separation between the equipment and receiver.
- Connect the equipment into an outlet on a circuit different from that to which the receiver is connected.
- Consult the dealer or an experienced radio/TV technician for help.

## **FCC Radiation Exposure Statement:**

This equipment complies with FCC radiation exposure limits set forth for an uncontrolled environment.

This equipment should be installed and operated with minimum distance 20cm between the radiator & your body.

# Orderable part number/Model no. comparison table

Orderable p	Model no.	BLE/Wi-Fi	LTE Cat-M	LoRa(WAN)	Security el
art number			1/ NB-IoT		ement

SGW3531	F1s	1	/	<b>√</b>	✓
SGW3501	F1	1	1	1	×
SGW3431	F1/Cs	✓	/	×	✓
SGW3401	F1/C	<b>√</b>	/	×	×
SGW3231	F1/Ls	1	×	1	/
SGW3201	F1/L	1	×	<b>√</b>	×
SGW3131	F1/Ws	1	×	×	1
SGW3101	F1/W	1	×	×	×

# **Revision History**

Versio n	Released Dat e	Description	
1.0	Feb 7, 2024	Initial document release	

1.1	Mar 6, 2024	Branding revised with updates: Introduction: Operating temperature updated Section 4: Pi n number updated (A38 and A37) Section 5b: Link to MicroPython documentation library upd ated Section 6a: MSL updated
1.2	Jul 7, 2024	Adding following section: Section 7: Certification Section 8: Part number/Model no. comparison table

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# **Documents / Resources**



SG Wireless F1 Smart Module [pdf] User Manual

SGW3531, SGW3501, SGW3431, SGW3401, SGW3231, SGW3201, SG W3131, SGW3101, F1 Smart Module, F1, Smart Module, Module

### References

- User Manual
- SG

Wireless

▶ F1, F1 Smart Module, Module, SG Wireless, SGW3101, SGW3131, SGW3201, SGW3231, SGW3401, SGW3431, SGW3501, SGW3531, Smart Module

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